onsemi

Self-Protected Low Side Driver with Temperature and Current Limit

42 V, 10 A, Single N-Channel, DPAK

NCV8408, NCV8408B

NCV8408/B is a single channel protected Low–Side Smart Discrete device. The protection features include overcurrent, overtemperature, ESD and integrated Drain–to–Gate clamping for overvoltage protection. Thermal protection includes a latch which can be reset by toggling the input. This device is suitable for harsh automotive environments.

Features

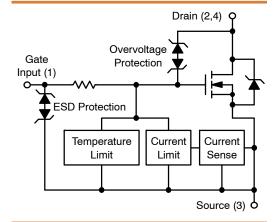
- Short Circuit Protection
- Thermal Shutdown with Latched Reset
- Gate Input Current Flag During Latched Fault Condition
- Overvoltage Protection
- Integrated Clamp for Inductive Switching
- ESD Protection
- dV/dt Robustness
- Analog Drive Capability (Logic Level Input)
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Switch a Variety of Resistive, Inductive and Capacitive Loads
- Can Replace Electromechanical Relays and Discrete Circuits
- Automotive / Industrial

V _{DSS} (Clamped)	R _{DS(on)} TYP	I _D MAX (Limited)
42 V	55 mΩ @ 5 V	10 A

DATA SHEET





ORDERING INFORMATION

Device	Package	Shipping [†]
NCV8408DTRKG	DPAK (Pb-Free)	2500/Tape & Reel
NCV8408BDTRKG	DPAK (Pb-Free)	2500/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage Internally Clamped	V _{DSS}	42	Vdc
Drain-to-Gate Voltage Internally Clamped $(R_{GS} = 1.0 \text{ M}\Omega)$	V _{DGR}	42	V
Gate-to-Source Voltage	V _{GS}	±14	Vdc
Continuous Drain Current	Ι _D	Internally L	imited
Gate Input Current (V _{GS} = ±14 V _{DC})	I _{GS}	±10	mA
Source to Drain Current	I _{SD}	4.0	A
Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 1) @ $T_A = 25^{\circ}C$ (Note 2)	PD	1.8 2.3	W
Thermal Resistance Junction-to-Ambient Steady State (Note 1) Junction-to-Ambient Steady State (Note 2) Junction-to-Tab Steady State (Note 3)	$f R_{ heta JA} \ R_{ heta JA} \ R_{ heta JA} \ R_{ heta JT}$	70 55 2.1	°C/W
Single Pulse Inductive Load Switching Energy ($V_{DD} = 20 \text{ Vdc}, V_{GS} = 5.0 \text{ V}, I_L = 8.0 \text{ A}$) Repetitive Pulse Inductive Load Switching Energy ($V_{DD} = 20 \text{ Vdc}, V_{GS} = 5.0 \text{ V}, I_L = 8.0 \text{ A}, T_J = 25^{\circ}\text{C}$) Repetitive Pulse Inductive Load Switching Energy ($V_{DD} = 20 \text{ Vdc}, V_{GS} = 5.0 \text{ V}, I_L = 6.8 \text{ A}, T_J = 105^{\circ}\text{C}$)	E _{AS} E _{AR} E _{AR}	185 128 92	mJ
Load Dump Voltage (V_{GS} = 0 and 10 V, R_I = 2.0 Ω , R _L = 4.5 Ω , t _d = 400 ms, T _J = 25°C)	V _{LD}	63	V
Operating Junction Temperature	TJ	-40 to 150	°C
Storage Temperature	T _{stg}	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Surface-mounted onto minimum pad FR4 PCB (1 oz Cu, 0.06" thick).
Surface-mounted onto 2" square FR4 PCB, (1" square, 1 oz Cu, 0.06" thick).
Surface-mounted onto minimum pad FR4 PCB (2 oz Cu, 0.06" thick).

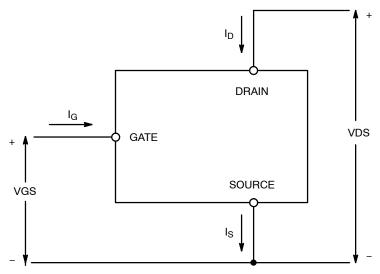


Figure 1. Voltage and Current Convention

Characteristic	Test Conditions	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•			•	
$\begin{array}{l} Drain-to-Source Clamped Breakdown Vol(V_{GS} = 0 V, I_D = 10 mA, T_J = 25^{\circ}C) \\ (V_{GS} = 0 V, I_D = 10 mA, T_J = 150^{\circ}C) \\ (Note(V_{GS} = 0 V, I_D = 10 mA, T_J = -40^{\circ}C) \\ (Note$	e 6)	V _{(BR)DSS}	42 40 43	46 45 47	51 51 51	V
Zero Gate Voltage Drain Current $(V_{GS} = 0 V, V_{DS} = 32 V, T_J = 25^{\circ}C)$ $(V_{GS} = 0 V, V_{DS} = 32 V, T_J = 150^{\circ}C)$ (Note 6)		I _{DSS}		0.6 2.5	5.0 10	μΑ
INPUT CHARACTERISTICS (Note 4)						
Gate Input Current – Normal Operation	(V _{GS} = 5.0 V)	I _{GSSF}	-	25	50	μA
Gate Input Current – Protection Latched	(V _{GS} = 5.0 V) (Note 6)	I _{GSSL}	-	440	-	μΑ
Gate Threshold Voltage	$(V_{GS} = V_{DS}, I_D = 1 \text{ mA})$	V _{GS(th)}	1.0	1.7	2.2	V
Gate Threshold Temperature Coefficient		V _{GS(th)} /T _J	-	5.0	-	-mV/°C
Latched Reset Voltage	(Note 6)	V _{LR}	0.8	1.4	1.9	V
Latched Reset Time	$(V_{GS} = 5.0 \text{ V to } V_{GS} < 1 \text{ V}) \text{ (Note 6)}$	t _{LR}	10	40	100	μs
Internal Gate Input Resistance			-	25.5	-	kΩ
ON CHARACTERISTICS (Note 4)		•			•	
$\begin{array}{l} \mbox{Static Drain-to-Source On-Resistance} \\ (V_{GS} = 5.0 \mbox{ V}, \mbox{ I}_{D} = 3.0 \mbox{ A}, \mbox{ T}_{J} @ 25^{\circ}\mbox{C}) \\ (V_{GS} = 5.0 \mbox{ V}, \mbox{ I}_{D} = 3.0 \mbox{ A}, \mbox{ T}_{J} @ 150^{\circ}\mbox{C}) \mbox{ (No. 1)} \end{array}$	ote 6)	R _{DS(on)}		55 100	60 120	mΩ
Source-Drain Forward On Voltage	(V _{GS} = 0 V, I _S = 7.0 A)	V _{SD}	-	0.95	-	V
SWITCHING CHARACTERISTICS (Note	6)	1			1	
Turn-OFF/ON Slew Rate Matching	$ \begin{array}{l} V_{GS} = 5.0 \; V, \; V_{DS} = 13 \; V, \; R_L = 4 \; \Omega; \\ T_J = -40^\circ C \\ T_J = 150^\circ C \\ T_J = 150^\circ C \\ T_J = 25^\circ C \\ -40^\circ C < T_J < 150^\circ C \end{array} $	T _{Match}	-15 -15 -5 -20	- - -	15 15 5 20	%
Turn-ON Delay Time		t _{d(ON)}		10	20	μs
Rise Time (10% I_D to 90% $I_D)$		t _r		20	40	1
Turn-OFF Delay Time	V _{GS} = 5 V, V _{DS} = 13 V	t _{d(OFF)}		30	60	
Fall Time (90% I _D to 10% I _D)	$R_{L} = 4 \Omega$, $-40^{\circ}C < T_{J} < 150^{\circ}C$	t _f		20	40	
Slew-Rate ON (90% V_D to 10% $V_D)$		-dV _{DS} /dt _{ON}		0.5		V/µs
Slew-Rate OFF (10% V_D to 90% V_D)		dV _{DS} /dt _{OFF}		0.5		
SELF PROTECTION CHARACTERISTIC	3 (T _J = 25°C unless otherwise noted) (1	Note 5)				
Current Limit V _{GS} = 5.0 V, V _{DS} = 10 V, T _J @ 25°C		I _{LIM}	10	13	16	A

			10 10 9	13 - -	16 18 16	
Temperature Limit (Turn-off)	V _{GS} = 5.0 V V _{GS} = 10 V	T _{LIM(off)}	150 150	175 165	200 185	°C

ESD ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Electro-Static Discharge Capability	Human Body Model (HBM)	ESD	4000	_	-	V
Electro-Static Discharge Capability	Machine Model (MM)	ESD	400	-	_	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width =[300 µs, Duty Cycle = 2%.

Fault conditions are viewed as beyond the normal operating range of the part.
Not subject to production testing.

TEST CIRCUITS AND WAVEFORMS

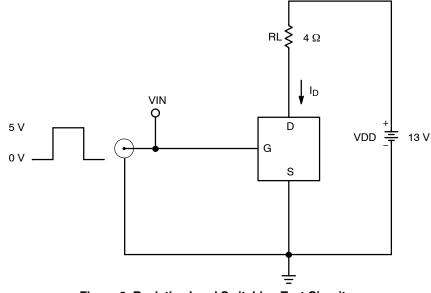


Figure 2. Resistive Load Switching Test Circuit

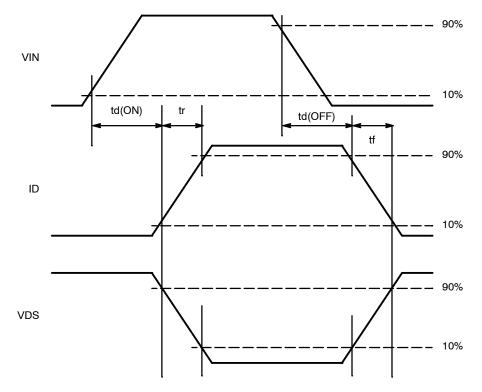


Figure 3. Resistive Load Switching Waveforms

TEST CIRCUITS AND WAVEFORMS

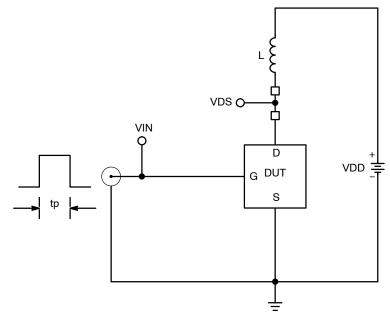
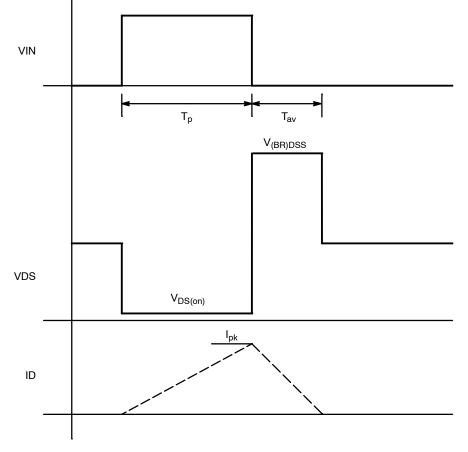
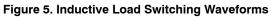
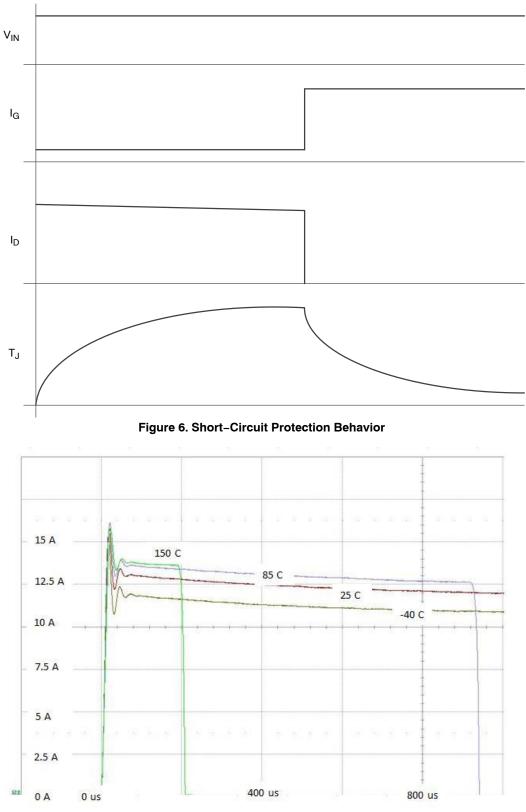


Figure 4. Inductive Load Switching Test Circuit

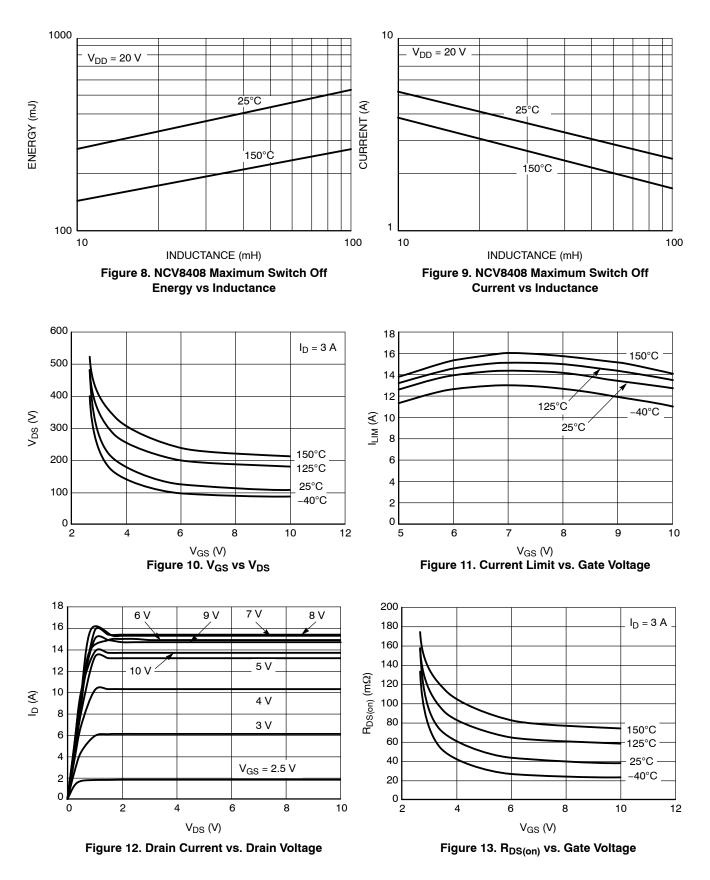




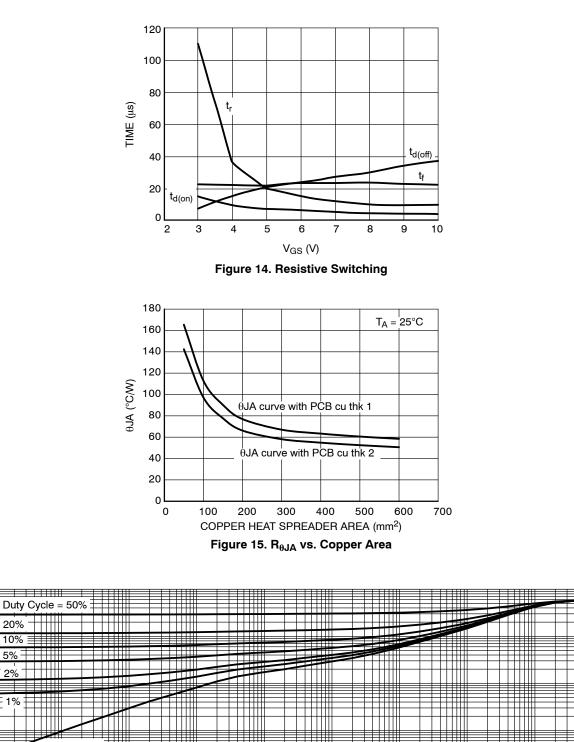




TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



100

10

1

0.1

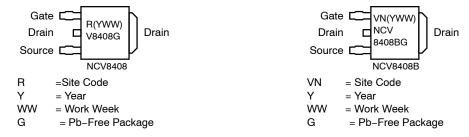
0.01

R(t) (°C/W)

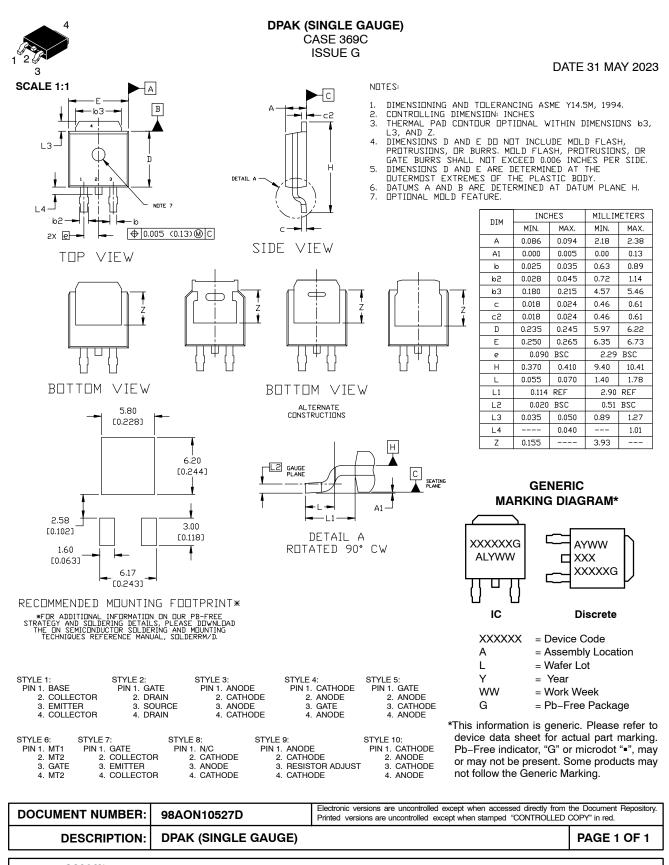
Single Pulse 0.00001 0.0001 0.001 0.01 0.1 1 10 100 1000 PULSE TIME (s)

Figure 16. Transient Thermal Resistance

MARKING DIAGRAMS



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